NSN 5961-01-213-1967

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Inclosure Material:

Plastic

Overall Length:

0.650 inches

Overall Height:

0.190 inches

Overall Width:

0.420 inches

Mounting Facility Quantity:

1

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-220ab

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 drain to source voltage and 50.0 drain to gate voltage

Current Rating Per Characteristic:

8.20 amperes drain current

Power Rating Per Characteristic:

40.0 watts total device dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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